



#### P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
-20V	$28m\Omega$ @ $V_{GS} = -4.5V$	-6.1A
-20 V	43mΩ @ V <sub>GS</sub> = -2.5V	-4.9A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Load Switch

#### **Features**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

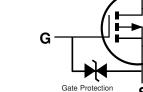
#### **Mechanical Data**

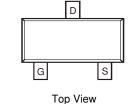
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (63)
- Terminal Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)





SOT23





Top View

Internal Schematic

**Ordering Information** (Note 4)

Part Number	Case	Packaging
DMP2037U-7	SOT23	3,000 / Tape & Reel
DMP2037U-13	SOT23	10,000 / Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



MP4 = Product Type Marking Code YM = Date Code Marking Y or $\overline{Y}$  = Year (ex: H = 2020) M = Month (ex: 9 = September)

### Date Code Key

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н	- 1	J	K	L	М	N	0	Р	R	S
NA 41-								Aum	C	0-4	Nav	Dec
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	שם



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	-20	V
Gate-Source Voltage		Vgss	±10	V
Continuous Drain Current (Note 6) Vgs = -4.5V	$T_C = +25$ °C $T_C = +70$ °C	lo	-6.1 -4.8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	-38	Α
Maximum Continuous Body Diode Forward Current (Note 6)		Is	-2.2	Α

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P <sub>D</sub>	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	158	°C/W
Total Power Dissipation (Note 6)		P <sub>D</sub>	1.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	81	°C/W
Thermal Resistance, Junction to Case (Note 7)		Rejc	14.3	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	$V_{GS} = 0V$ , $I_{D} = -1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	1	_	-1	μΑ	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	-	_	±10	μΑ	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.5	_	-1.2	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$	
Static Drain-Source On-Resistance	Dagger	l	20.3	28	mΩ	VGS = -4.5V, ID = -2A	
Static Drain-Source On-Nesistance	RDS(ON)	l	26.5	43	11122	$V_{GS} = -2.5V, I_D = -2A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.66	-1.1	V	$V_{GS} = 0V$ , $I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	803	_		101/11/01/	
Output Capacitance	Coss		114	_	pF	$V_{DS} = -10V$ , $V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	51	_		I = IIVII IZ	
Gate Resistance	Rg	_	65.5	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -8V)	$Q_g$	_	14.5	_			
Total Gate Charge (V <sub>GS</sub> = -4.5V)	$Q_g$	_	8.4	_	nC	\/ 10\/ I- 00A	
Gate-Source Charge	Qgs	_	1.5	_	IIC	V <sub>DD</sub> = -10V, I <sub>D</sub> = -20A	
Gate-Drain Charge	$Q_{gd}$		1.9	_			
Turn-On Delay Time	td(on)	_	12	_			
Turn-On Rise Time	tR	_	6	_	200	$V_{GS} = -4.5V, V_{DD} = -10V,$	
Turn-Off Delay Time	tD(OFF)		81	_	ns	$R_G = 1\Omega$ , $I_D = -10A$	
Turn-Off Fall Time	tF	_	46	_			

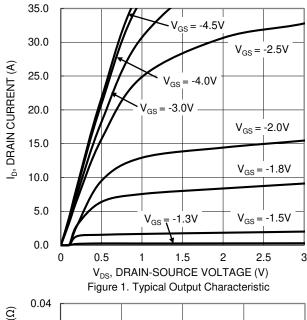
Notes:

<sup>5.</sup> Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.

<sup>9.</sup> Short duration pulse test used to minimize self-heating effect.

<sup>10.</sup> Guaranteed by design. Not subject to product testing.





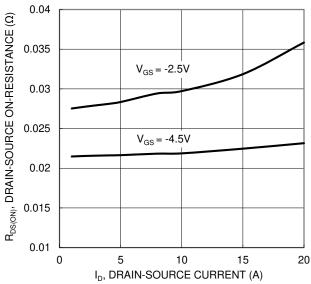


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

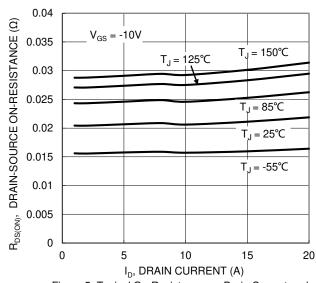
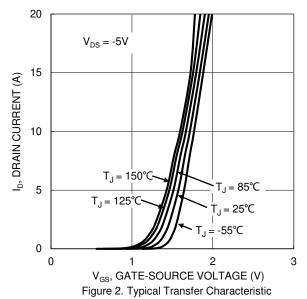
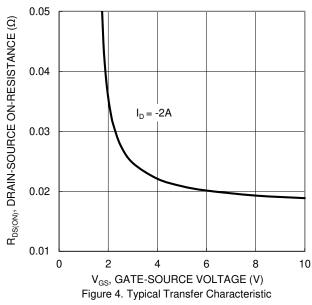


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





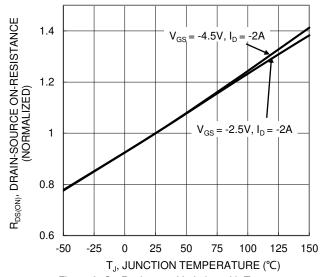


Figure 6. On-Resistance Variation with Temperature



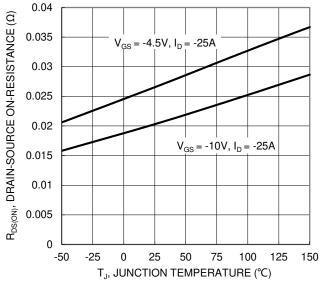


Figure 7. On-Resistance Variation with Temperature

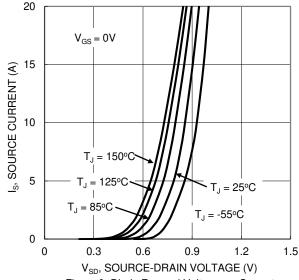


Figure 9. Diode Forward Voltage vs. Current

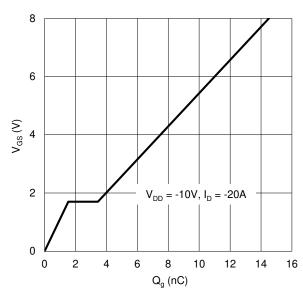


Figure 11. Gate Charge

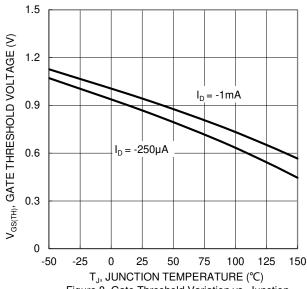
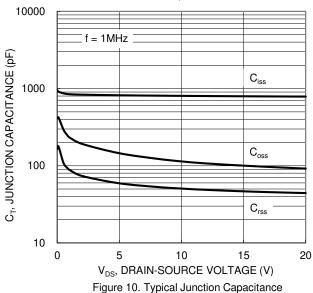


Figure 8. Gate Threshold Variation vs. Junction Temperature



100 R<sub>DS(ON)</sub> Limited 100µs 10 ID, DRAIN CURRENT (A) = 10ms  $P_W = 100 \text{ms}$ T<sub>J(Max)</sub> = 150°C  $T_C = 25^{\circ}C$ Single Pulse DUT on 1\*MRP board  $V_{GS} = -4.5V$ 0.01 0.1 10 100 V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



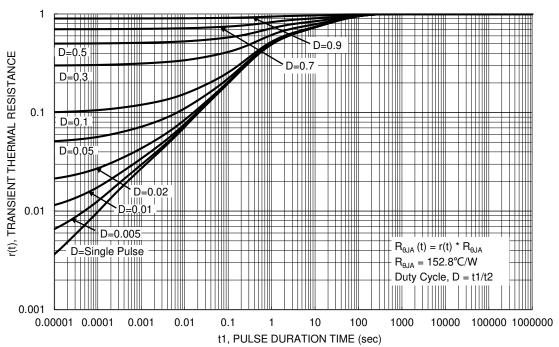


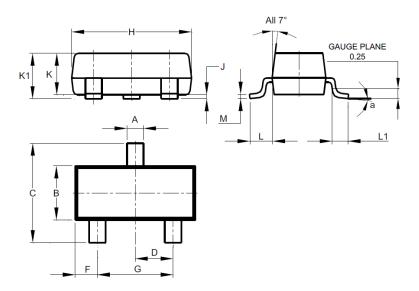
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

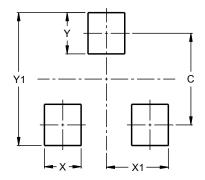


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
C	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
V4	0.0



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